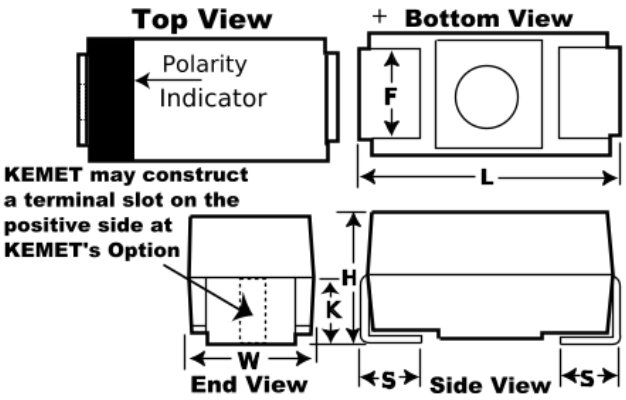
T498C335M025ZTE2K07280

Obsolete

B45196P, Tantalum, MnO2 Tantalum, High Temperature, 3.3 uF, 20%, 25 VDC, SMD, Molded, High Temperature, N/A, 2 Ohms, 6032, Height Max = 2.8mm



General Information	
Series	B45196P
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Notes	Obsolete.

Dimensions	
Footprint	6032
L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
K	1.8mm TYP

Specifications	
Capacitance	3.3 uF
Capacitance Tolerance	20%
Voltage DC	25 VDC (85C), 19.92 VDC (125C), 16.75 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5%
Failure Rate	N/A
Resistance	2 Ohms (100kHz)
Ripple Current	234.5 mAmps (25C), 211.1 mAmps (85C), 93.8 mAmps (125C)
Leakage Current	0.9 uA

Packaging Specifications	
Packaging	T&R, 330mm
Packaging Quantity	3000

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